



Multipaction Analysis in Traveling Wave Tubes

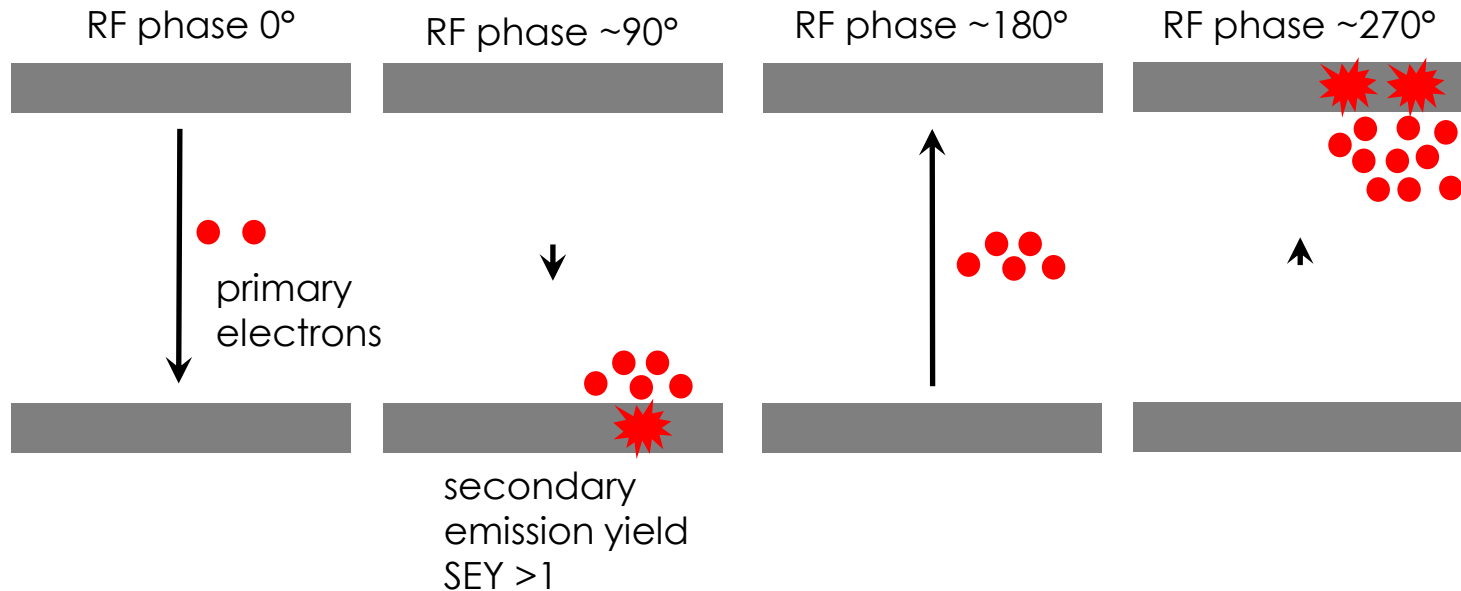
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What is Multipaction?

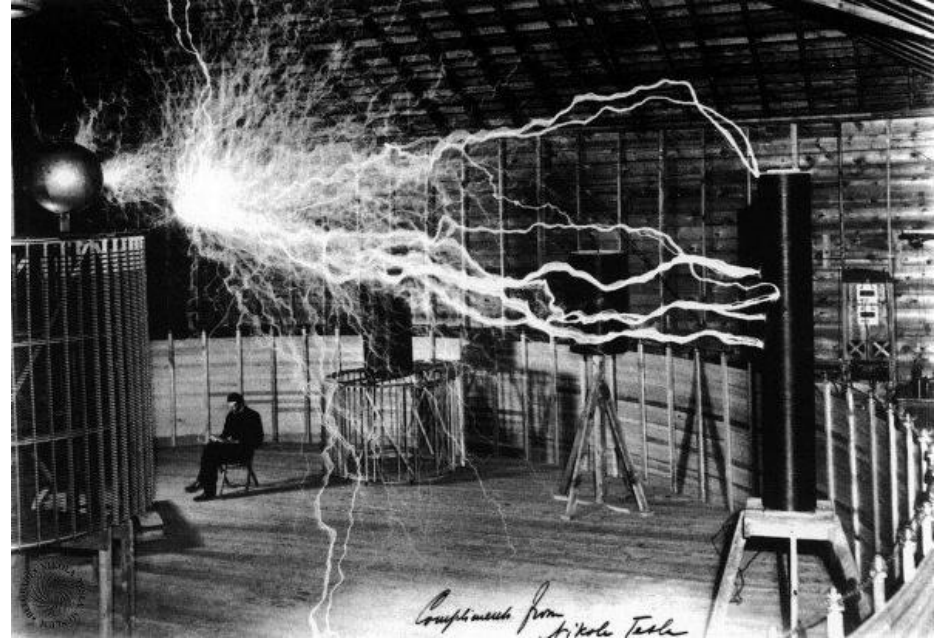
Multipaction: Electron avalanche effect

Prerequisites: High-power RF fields, material with $SEY > 1$, timing, vacuum



Problems of Multipaction

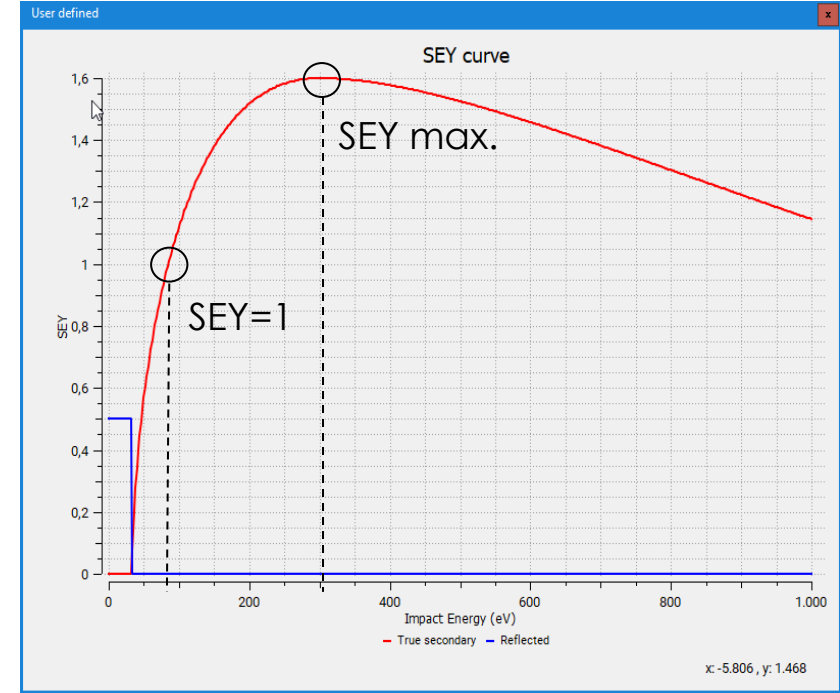
- Device damage through thermal effects
- Signal distortion
- Consequence: Device has to be multipaction-free!
- Analysis or testing required
 - Here: focus on analysis
 - (testing notoriously difficult)



NOT Multipaction

Material Parameter: Secondary Electron Yield

- „How many secondary electrons are emitted upon impact of primary electron?“
- $SEY < 1$: no multiplication possible
 - Minimum power for multiplication
- Also dependent on angle of impact
- Great variation between materials



SEY: Secondary Electron Yield
from SPARK3D

Device Geometry and Analytical Solution (Level-1 Analysis)

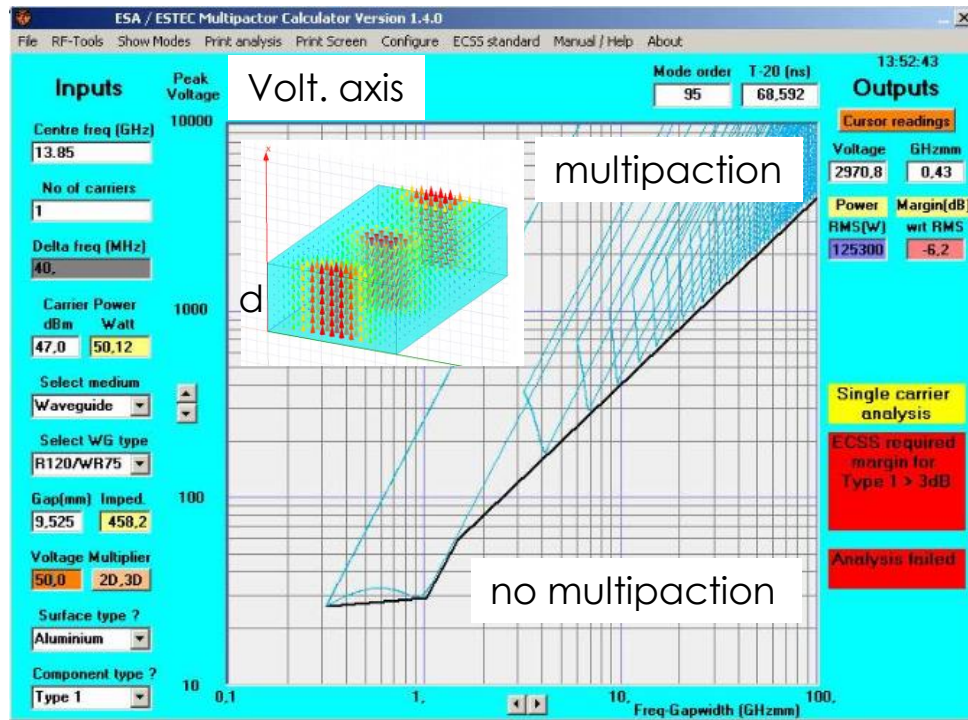
Analytical solution for homogeneous RF fields

➤ Example: Rectangular waveguide

Gap-Frequency product $f \cdot d$ crucial (in GHz * mm)

$f \cdot d$ close to unity: Device especially critical

Lower cut-off for $f \cdot d$

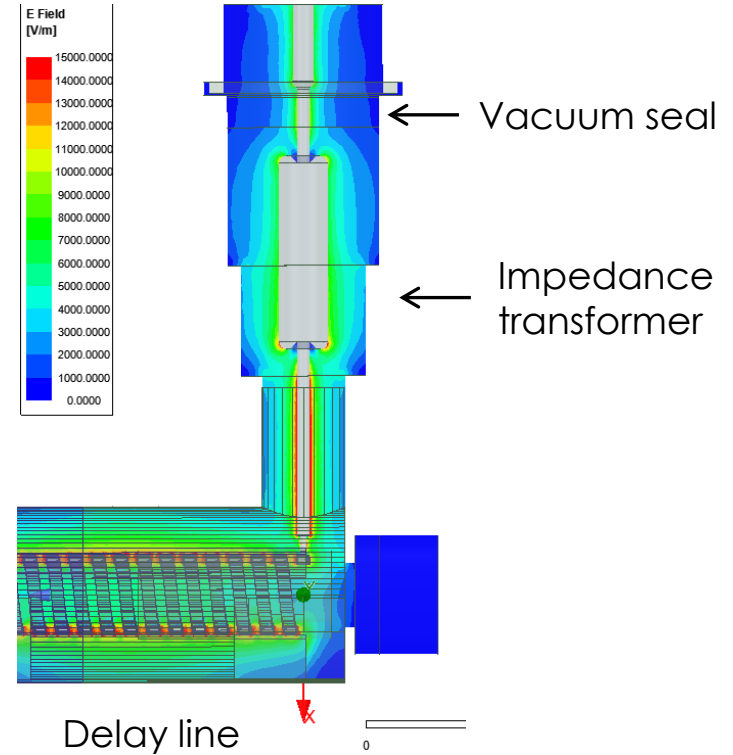
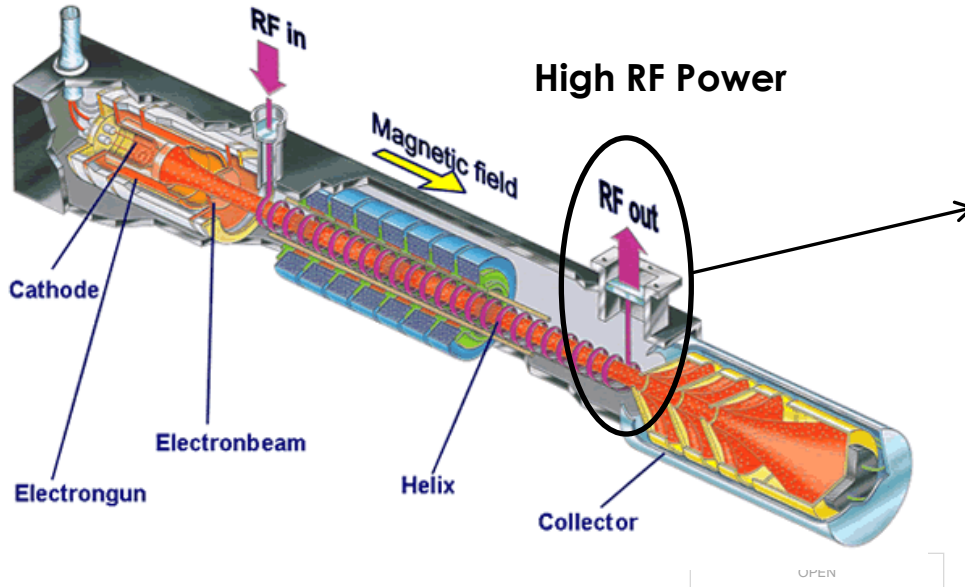


$f \cdot d$ axis

Multipaction in TWTs

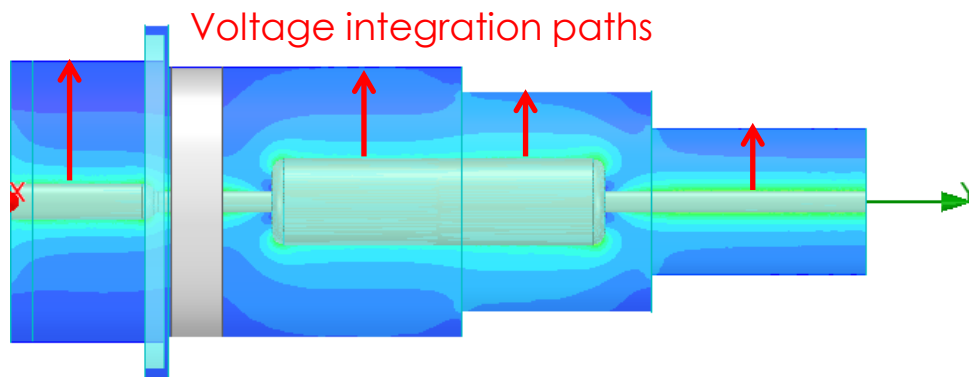
■ **Multipaction: High power, small gaps, low frequency**

■ **TWT: End of delay line, output coupler**



Non-Uniform Structures (Level-2 Analysis)

- Impedance transformers, filters etc.: Standing-wave patterns
- RF analysis with numerical solver (e.g. HFSS, CST)
- Integration of peak E-field to obtain peak voltage
- Continue as in Level-1 analysis



OPEN

When is a Level-2 Analysis not good enough?

Non-homogeneous RF fields

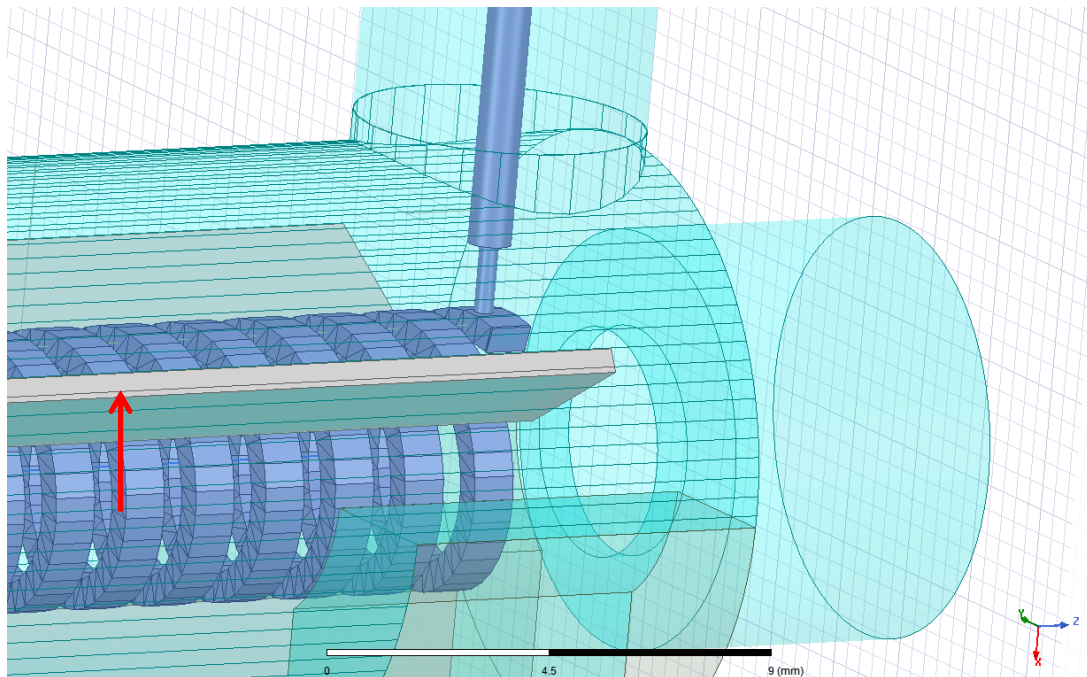
- High-impedance coax
- Any complicated geometry

Static electric fields

- TWT: no issue

Static magnetic fields

- TWT: PPM focusing field (several 0.1 T)



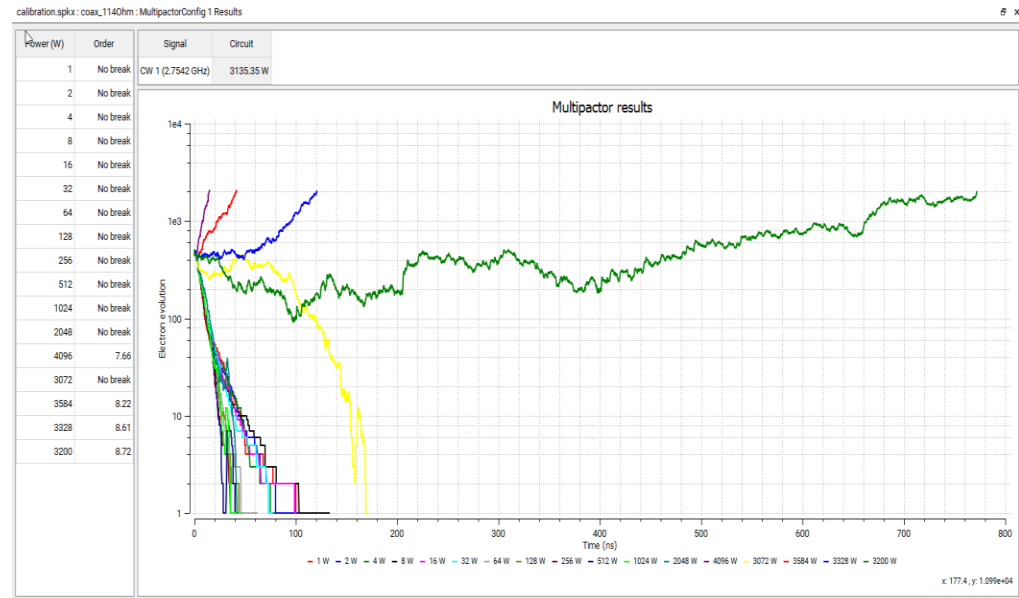
Level-3 Analysis: Time-Domain Tracking of Electrons

Commercial code: SPARK3D

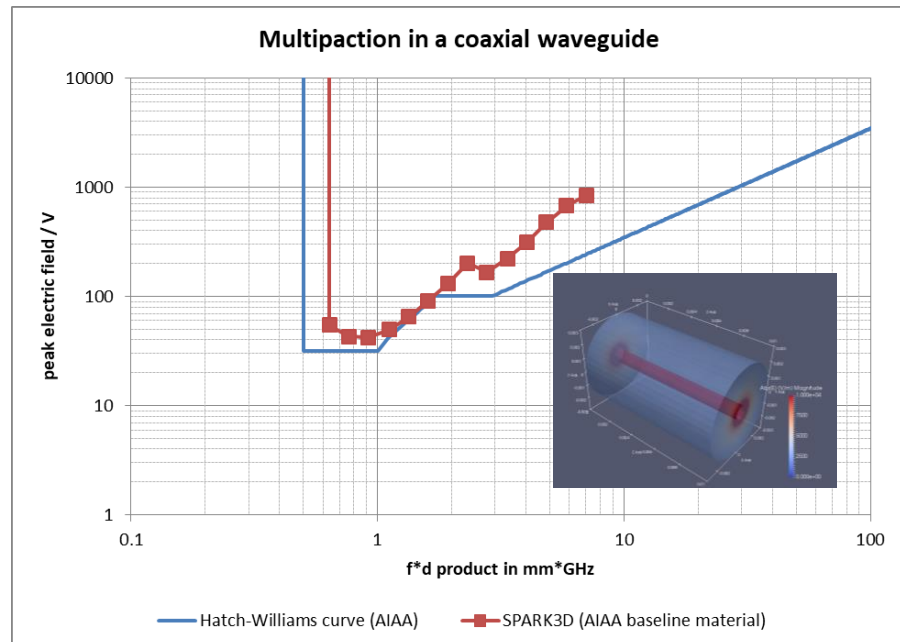
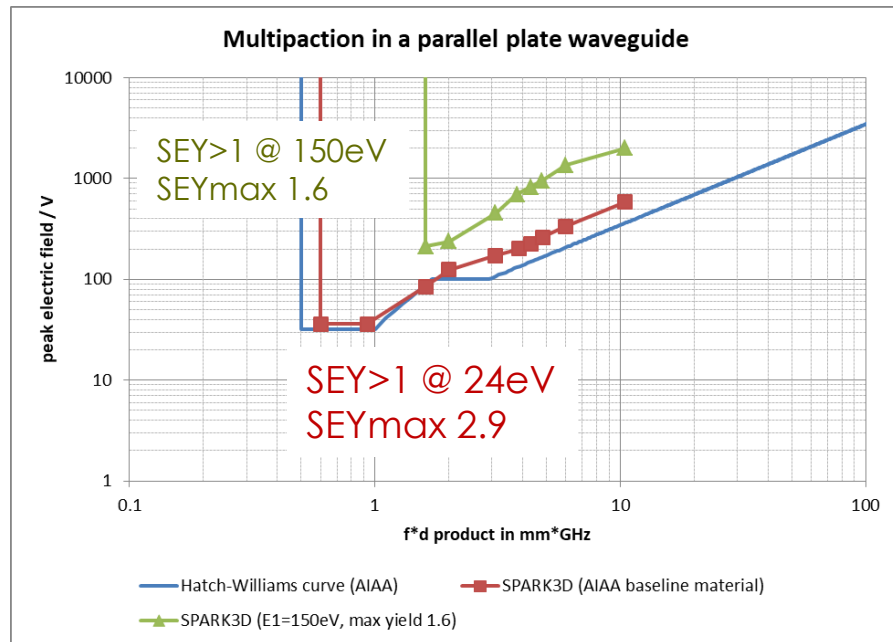
- Part of the CST Suite

Workflow:

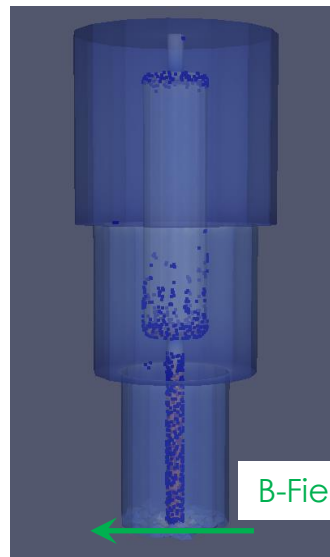
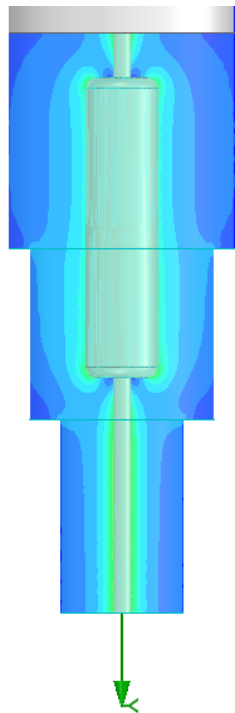
- Import RF fields from HFSS, CST, or FEST
- Define material
- Define static fields (E and/or B)
- Seed electrons
- Track electrons including secondary emission
- Growing number of electrons: multiplication



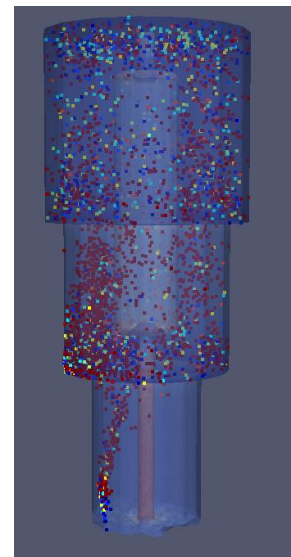
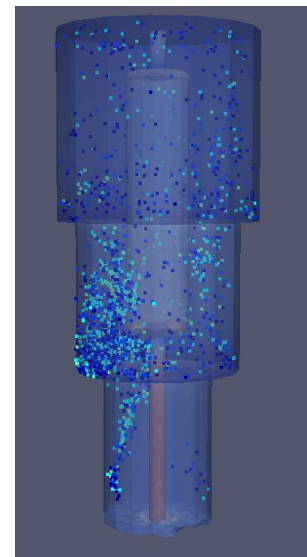
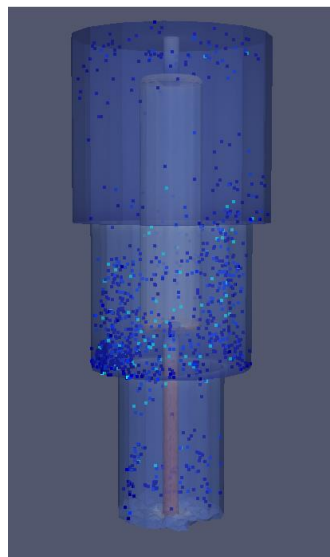
Analytical Solution vs. SPARK3D



Multipaction in the output coupler (vacuum envelope) 1/2



B-Field

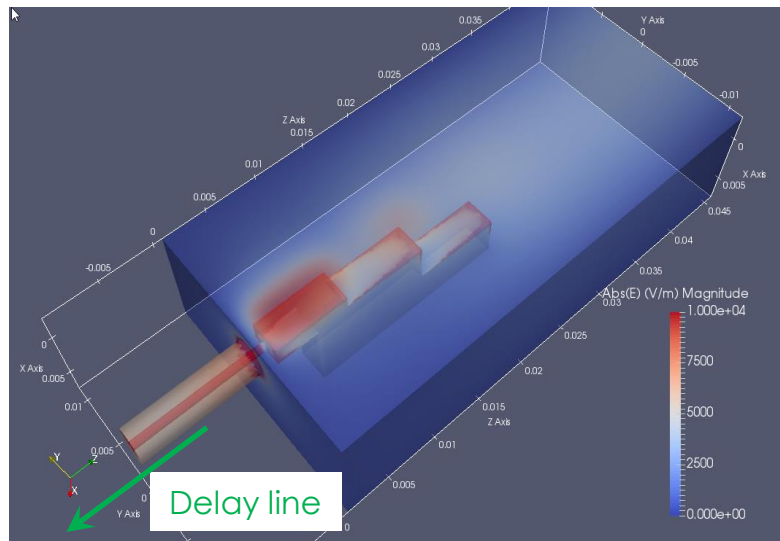


Time (~20ns)

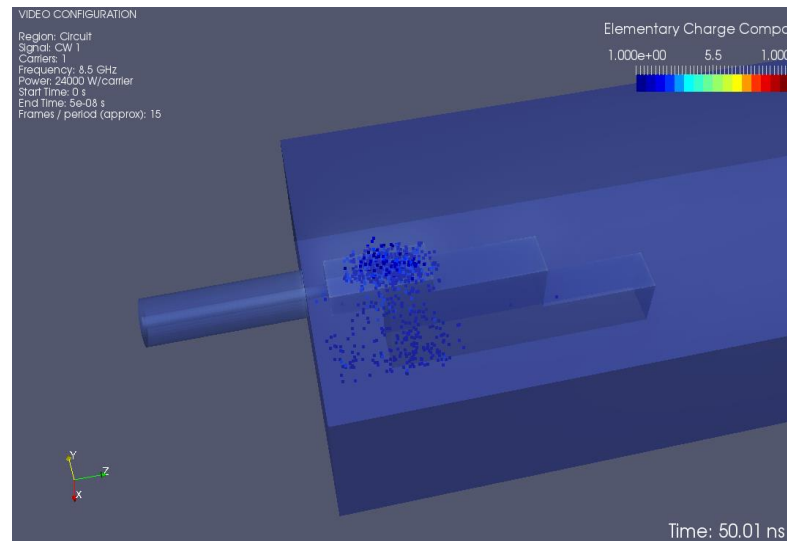
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Multipaction in the output coupler (vacuum envelope) 2/2

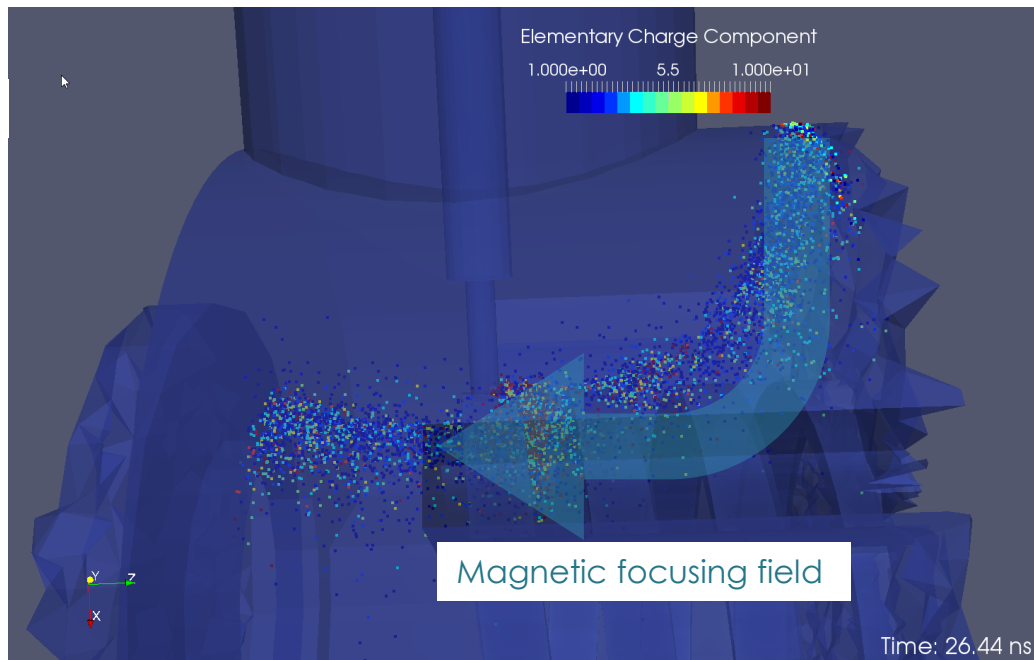
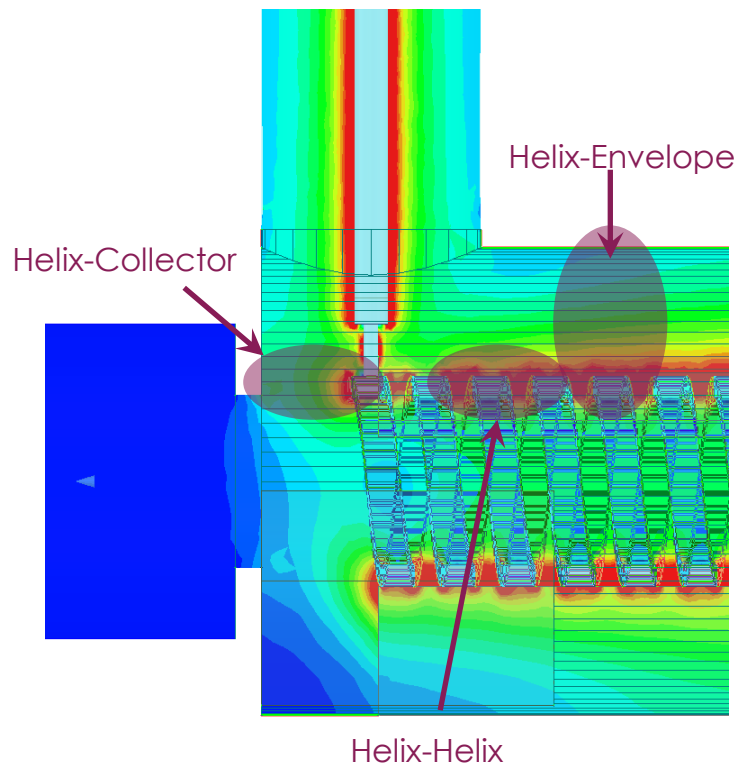


E-Field as imported from HFSS



Multipaction electron cloud

Multipaction in the delay line



What can we do against multiplication?

■ **Geometry: Keep the gaps far away from $f \cdot d = 1$**

■ **Baking [1]: SEY is reduced by evacuation and heating**

➤ TWTs are evacuated at $>450^\circ\text{C}$

■ **Electron/Ion bombardment [2]**

➤ Fortunately there are a lot of scattered electrons in a TWT

[1] Christian Scheuerlein "The Influence of an Air Exposure on the Secondary Electron Yield of Copper", CERN, Master Thesis, ISBN 9783832454326

[2] Role of the different chemical components in the conditioning process of air exposer copper surfaces, Physical review accelerators and beams 22, CERN & ONERA, 08/2019

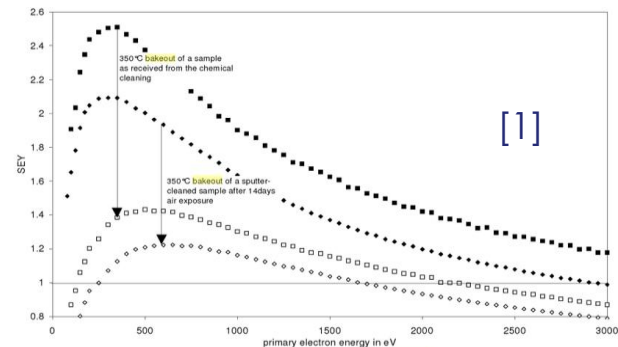
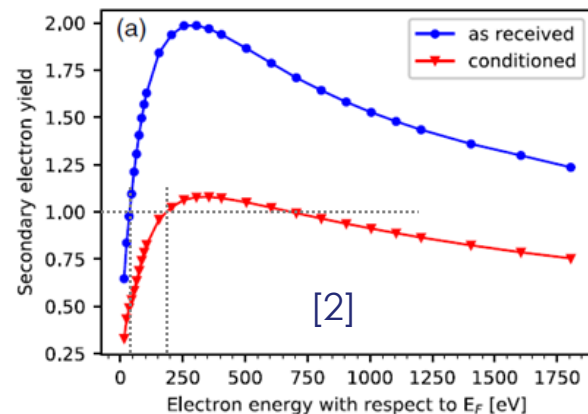


Figure 20: Difference of the secondary electron emission after a 350°C bakeout of a sample as received and after a 350°C bakeout of a sample which had been sputtercleaned and then exposed to air for 14 days



Summary

- TWTs are required to be multipaction-free
- Level-1 analysis (purely analytical): Fast, but strictly limited scope
- Level-2 analysis (numerical/analytical): More precise, but still limited
 - Relatively simple geometry, no static fields
- Level-3 analysis (numerical): Most reliable, but time-consuming
- Sensitivity greatly dependent on material parameters
- So far, no final TWT design has exhibited multipaction effects